

VOLTAGE REGULATORS, RELAY DRIVERS
LAMP DRIVERS, ELECTRICAL EQUIPMENT

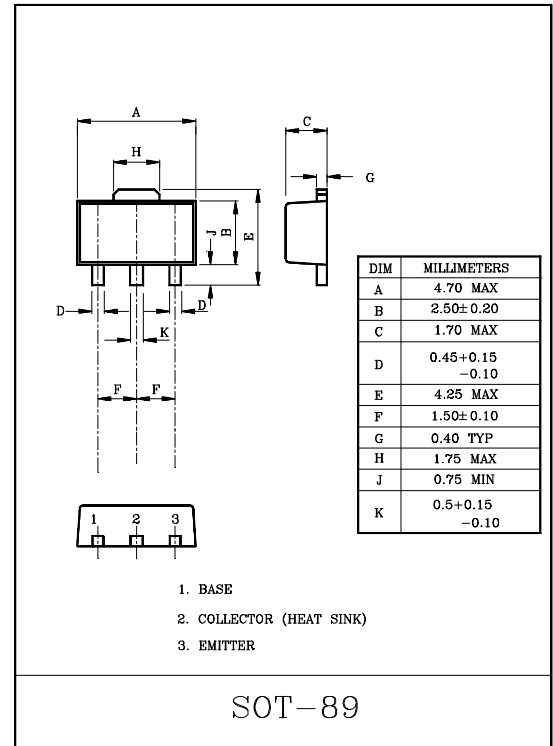
FEATURES

- Adoption of MBIT processes.
- Low collector-to-emitter saturation voltage.
- Fast switching speed.
- Large current capacity and wide ASO.
- Complementary to KTD1624.

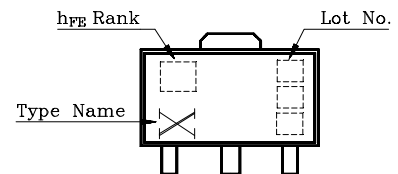
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CB0}	-60	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-6	V
Collector Current	I_C	-3	A
Collector Current(Pulse)	I_{CP}	-6	A
Collector Power Dissipation	P_C	500	mW
	P_{C^*}	1	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

* : Package mounted on ceramic substrate(250mm²×8t)



Marking

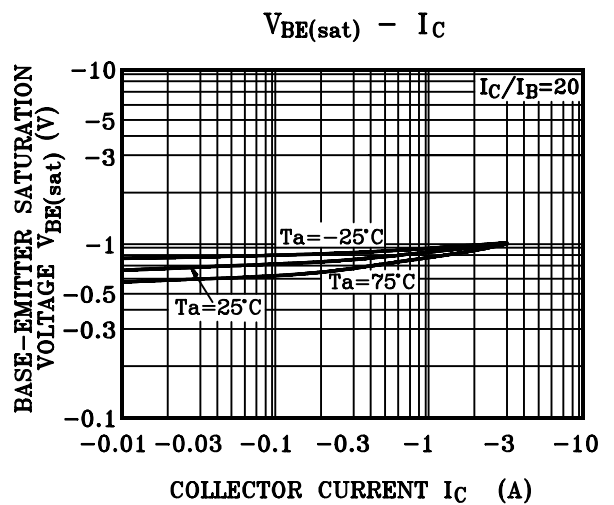
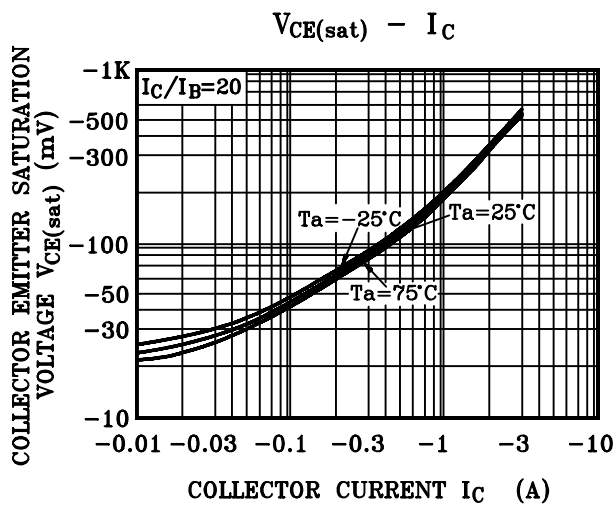
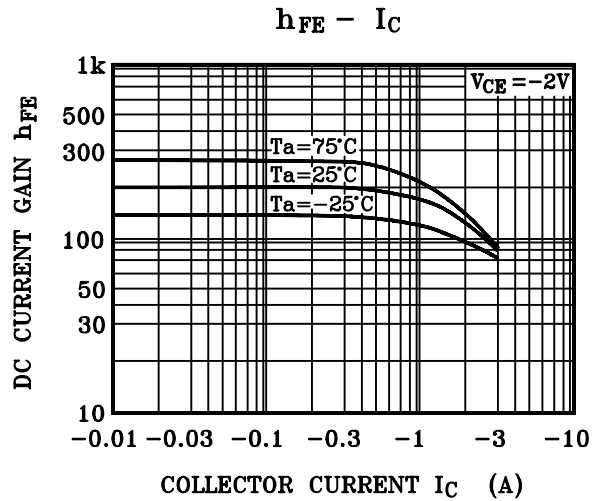
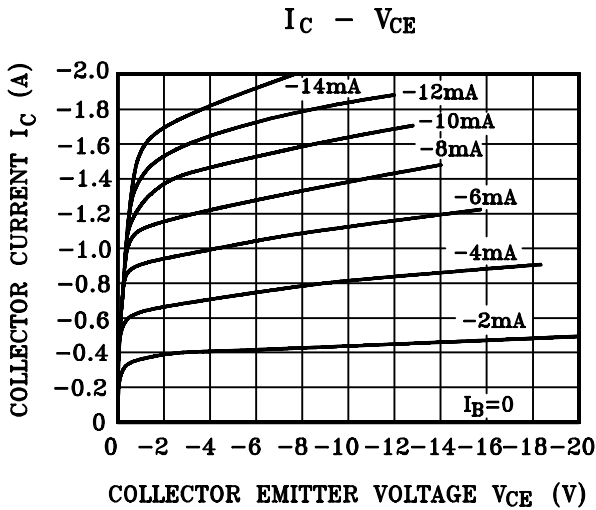
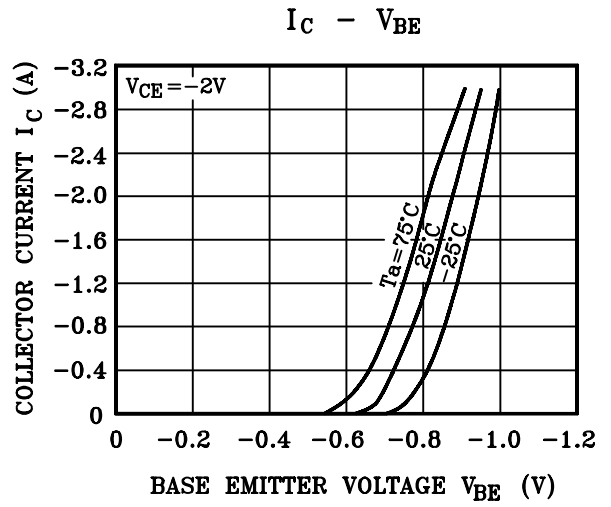
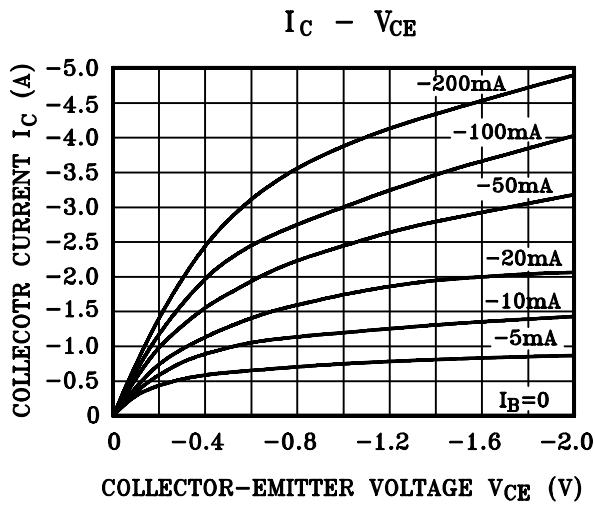


ELECTRICAL CHARACTERISTICS (T_a=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT.
Collector Cut-off Current	I_{CBO}	$V_{CB}=-40V, I_E=0$	-	-	-1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-4V, I_C=0$	-	-	-1	μA
DC Current Gain	$h_{FE} (1)$ (Note)	$V_{CE}=-2V, I_C=-100mA$	100	-	400	
	$h_{FE} (2)$	$V_{CE}=-2V, I_C=-3A$	35	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-2A, I_B=-100mA$	-	-0.35	-0.7	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-2A, I_B=-100mA$	-	-0.94	-1.2	V
Transition Frequency	f_T	$V_{CE}=-10V, I_C=-50mA$	-	150	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V, f=1MHz$	-	39	-	pF
Switching Time	Turn-on Time	t_{on}	-	70	-	nS
	Storage Time	t_{stg}	-	450	-	
	Fall Time	t_f	-	35	-	

-10I_{B1}=10I_{B2}=I_C=1A

Note : $h_{FE} (1)$ Classification A:100~200, B:140~280, C:200~400



KTB1124

